

isc Silicon NPN Power Transistor

DESCRIPTION

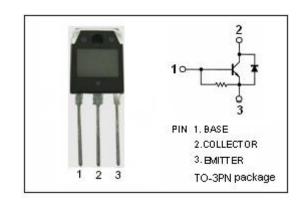
- · High Breakdown Voltage-
- : V_{CBO}= 1500V (Min)
- · High Switching Speed
- · High Reliability
- · Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

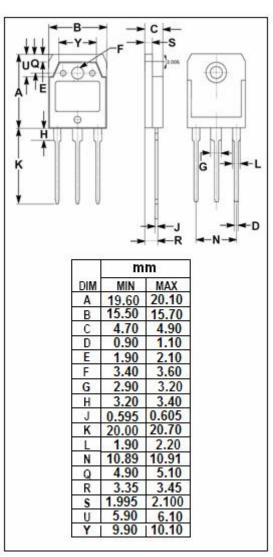
APPLICATIONS

 Designed for high definition CRT display horizontal deflection output applications.



SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	1500	V
V _{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current- Continuous	5	А
Іср	Collector Current-Pulse	16	А
Pc	Collector Power Dissipation @ T _C =25℃	120	W
Тл	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C







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2SC3481

ELECTRICAL CHARACTERISTICS

Tc=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; R _{BE} = ∞	800			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 5mA; I _E = 0	1500			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 200mA; I _C = 0	7			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4A; I _B = 1A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 4A; I _B = 1A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V; I _E = 0			10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0	40		130	mA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 5V	8			
V _{ECF}	C-E Diode Forward Voltage	I _F = 5A			2.0	V
f⊤	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 10V		3		MHz
t _{stg}	Storage Time	I _C = 4A, I _{B1} = 0.8A; I _{B2} = -1.6A;			3.0	μS
tf	Fall Time	R _L = 50Ω ; V _{CC} = $200 V$			0.3	μS

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